



M T B F (E I A J R C R - 9 1 0 2)

Model	BRDS100
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No.	P a r t s		Q'ty of Device	Failure rate [10 ⁻⁶ /H]	R e f e r e n c e
1	I C	Monolithic	8	0.2500	
2		Hybrid	0	0.0000	
3	Transistors		15	1.1913	
4	Diodes		7	0.1350	
5	LED•Optocouplers		0	0.0000	
6	Resistors		86	0.6568	
7	Capacitors		56	0.4144	
8	Transformer•Choke Coil		2	0.0460	
9	Connectors		506	0.0697	
10	Others		1	0.1100	
Total Failure Rate [10 ⁻⁶ /H]				2.8732	

M T B F	[H]	348,000
Ambient Temperature	[℃]	—
Load Factor	[%]	—